## NSN 5962-01-226-2274

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches	and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dis	sipation Rating:
739.0 milliwatts	
Operating Tempurate	re Range:
55.0/+125.0 degrees	celsius
Storage Tempurature	Range:
65.0/+150.0 degrees	celsius
End Application:	
An/bps14to15e	
Features Provided:	
lermetically sealed a	d burn in and bipolar and schottky and programmable and w/active pull-up
nclosure Material:	
Ceramic	
nclosure Configurat	on:
Dual-in-line	
Dutput Logic Form:	
Fransistor-transistor lo	gic
nput Circuit Pattern	
0 input	
Case Outline Source	And Designator:
D-2 mil-m-38510	
Ferminal Surface Tre	atment:
Solder	
/oltage Rating And 1	ype Per Characteristic:
7.0 volts power sourc	
Time Rating Per Cha	steristic:
75.00 nanoseconds p	opagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	
Rom	
Memory Capacity:	
Unknown	
Test Data Document	
96906-mil-std-883 sta	idard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And G	uantity:
16 printed circuit	
Shelf Life:	
N/a	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

